

## **GBU4A thru GBU4G**

# Single Phase Glass Passivated Silicon Bridge Rectifier

 $V_{RRM} = 50 \text{ V} - 400 \text{ V}$  $I_{O} = 4 \text{ A}$ 

#### **Features**

 Plastic package has Underwriters Laboratory Flammability Classification 94V-0

- ullet High case dielectric strength of 1500  $V_{\text{RMS}}$
- · Glass passivated chip junction
- · Ideal for printed circuit boards
- · High surge overload rating
- High temperature soldering guaranteed: 260°C/ 10 seconds, 0.375 (9.5mm) lead length
- · Not ESD Sensitive



Case: Molded plastic body over passivated junctions

Terminals: Plated leads, solderable per MIL-STD-750 Method 2026.

Mounting position: Any

#### **GBU Package**







Maximum ratings at Tc = 25 °C, unless otherwise specified

Parameter	Symbol	Conditions	GBU4A	GBU4B	GBU4D	GBU4G	Unit
Repetitive peak reverse voltage	V <sub>RRM</sub>		50	100	200	400	V
RMS reverse voltage	V <sub>RMS</sub>		35	70	140	280	V
DC blocking voltage	V <sub>DC</sub>		50	100	200	400	V
Operating temperature	T <sub>j</sub>		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C
Storage temperature	T <sub>stq</sub>		-55 to 150	-55 to 150	-55 to 150	-55 to 150	°C

#### Electrical characteristics at Tc = 25 °C, unless otherwise specified

Single phase, half sine wave, 60 Hz, resistive or inductive load

For capacitive load derate current by 20%

Parameter	Symbol	Conditions	GBU4A	GBU4B	GBU4D	GBU4G	Unit
Maximum average forward rectified current <sup>1,2</sup>	I <sub>O</sub>	T <sub>c</sub> = 100 °C	4.0	4.0	4.0	4.0	А
Peak forward surge current	I <sub>FSM</sub>	$t_p = 8.3 \text{ ms}$ , half sine	150	150	150	150	Α
Maximum instantaneous forward voltage drop per leg	V <sub>F</sub>	I <sub>F</sub> = 4 A	1.1	1.1	1.1	1.1	V
Maximum DC reverse current at rated DC blocking voltage per leg	I <sub>R</sub>	T <sub>a</sub> = 25 °C T <sub>a</sub> = 125 °C	5 500	5 500	5 500	5 500	μΑ
Rating for fusing	l <sup>2</sup> t	t < 8.3 ms	93	93	93	93	A <sup>2</sup> sec
Typical junction capacitance per leg <sup>3</sup>	C <sub>j</sub>		100	100	100	100	pF
Typical thermal resistance per leg <sup>1,2</sup>	$R_{\Theta JA}$		22	22	22	22	
	$R_{\Theta JL}$		4.2	4.2	4.2	4.2	°C/W

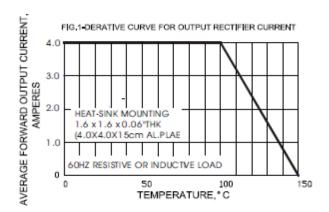
<sup>&</sup>lt;sup>1</sup> - Device mounted on 40 mm x 40 mm x 1.5 mm Al plate heatsink

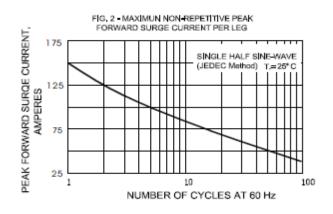
<sup>&</sup>lt;sup>2</sup> - Recommended mounted position is to bolt down device on a heatsink with silicon thermal compond for maximum heat transfer using #6 screw.

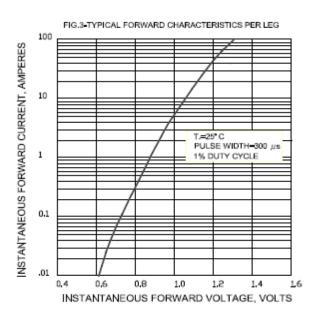
<sup>&</sup>lt;sup>3</sup> - Measured at 1.0 MHz and applied reverse bias of 4.0 V

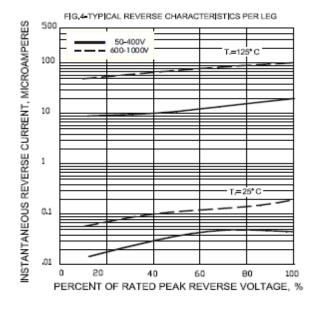


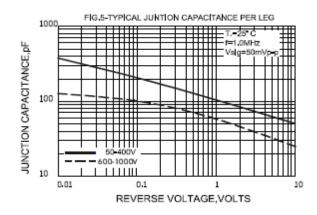
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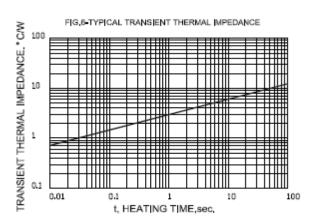










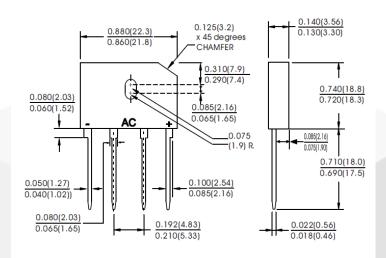




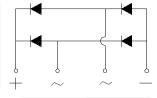
### Package dimensions and terminal configuration

Product is marked with part number and terminal configuration.

## GBU



Dimensions in inches and (millimeters)



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